

MSKSEMI 美森科

SEMICONDUCTOR



ESD



TVS



TSS



MOV



GDT



PLED

MBRA320T3G-MS THRU MBRA310T3G-MS Product specification

VOLTAGE RANGE: 20 - 100V

CURRENT: 3.0 A

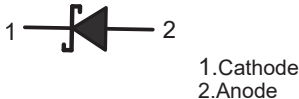
Features

- For Surface Mounted Applications
- High Temperature Metallurgically Bonded Contacts
- Plastic Material - UL Flammability
- Classification 94V-0
- High Reliability
- High Current Capability and Low VF
- Submersible Temperature of 265C for 10 Seconds in Solder Bath

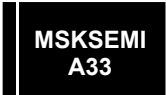
MECHANICAL DATA

- Case:SMA(DO-214AC), Molded Plastic
- Terminals: Solderable per MIL-STD-202,
- Method 208
- Polarity: Cathode Band
- Mounting Position: Any
- Weight: 0.064 grams (approx.)

Reference News

SMA(DO-214AC)	Schematic Diagram
	

Marking

MBRA320T3G-MS	MBRA330T3G-MS	MBRA340T3G-MS	MBRA350T3G-MS
			

MBRA360T3G-MS	MBRA380T3G-MS	MBRA390T3G-MS	MBRA3100T3G-MS
			

Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	MBRA 320 T3G-MS	MBRA 330 T3G-MS	MBRA 340 T3G-MS	MBRA 350 T3G-MS	MBRA 360 T3G-MS	MBRA 380 T3G-MS	MBRA 390 T3G-MS	MBRA 3100 T3G-MS	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	20	30	40	50	60	80	90	100	V
RMS Reverse Voltage	V _{R(RMS)}	14	21	28	35	42	56	64	71	V
Average Rectified Output Current @T _L = 105°C	I _O	3.0								A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	80								
Forward Voltage @I _F = 2.0A	V _{FM}	0.50			0.70		0.85			V
Peak Reverse Current At Rated DC Blocking Voltage @T _A = 25°C @T _A = 100°C	I _{RM}	1.0 20								mA
Typical Thermal Resistance (Note 1)	R _{θJL} R _{θJA}	10 50								°C/W
Operating Temperature Range	T _j	-65 to +125								°C
Storage Temperature Range	T _{STG}	-65 to +150								°C

Note: 1. Mounted on P.C. Board with 8.0mm² copper pad area.

FIG. 1 - FORWARD CURRENT DERATING CURVE

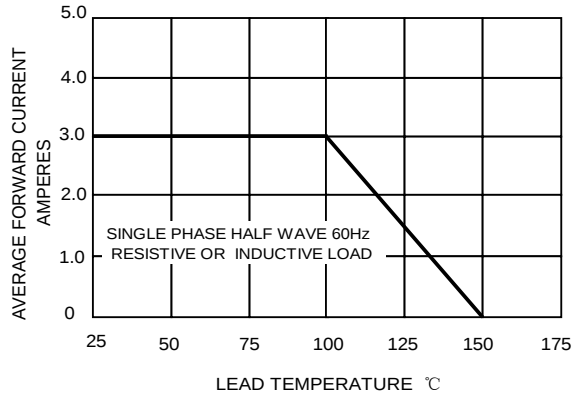


FIG. 2 - MAXIMUM NON-REPETITIVE SURGE CURRENT

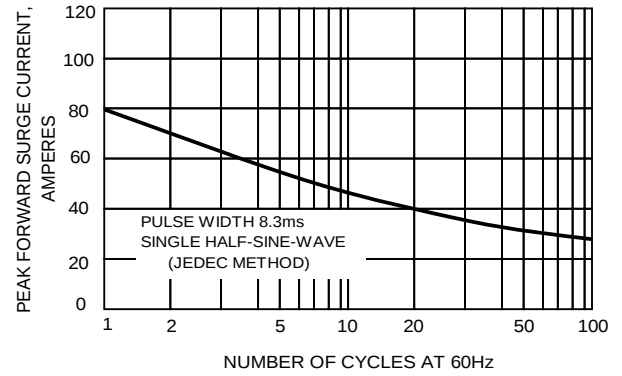


FIG. 3-TYPICAL FORWARD CHARACTERISTICS

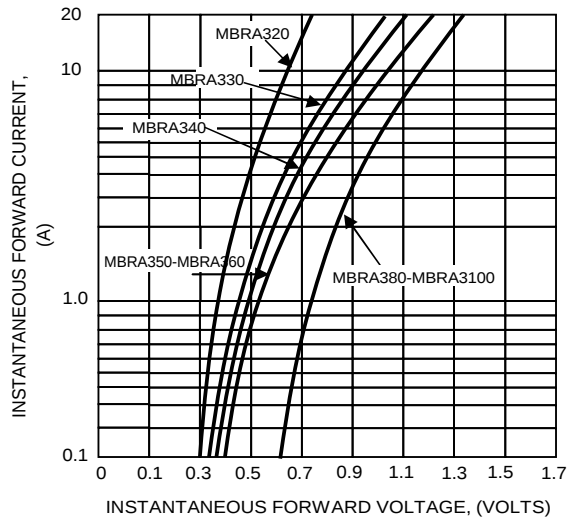


FIG. 4-TYPICAL JUNCTION CAPACITANCE

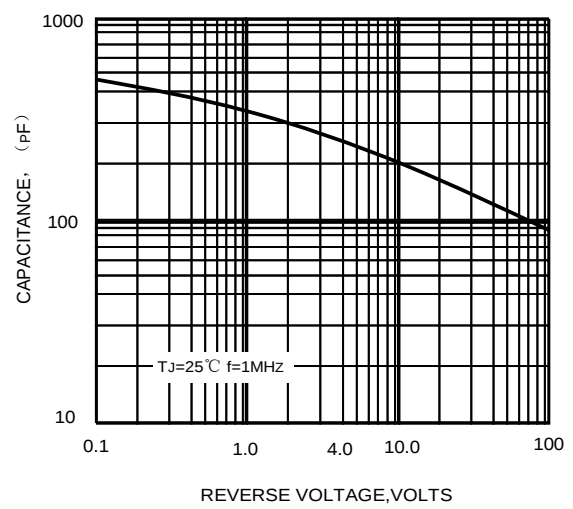
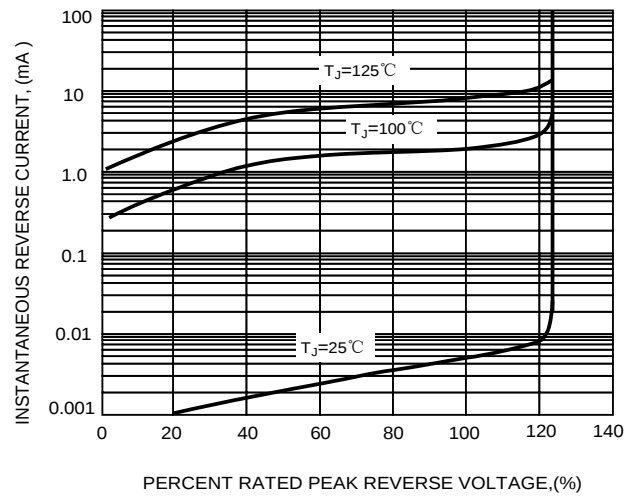
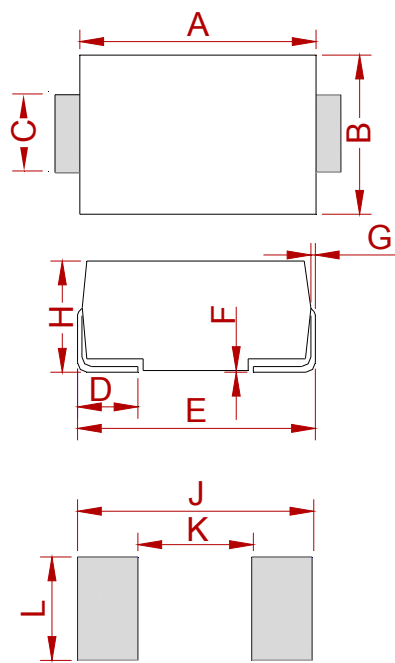


FIG. 5-TYPICAL REVERSE CHARACTERISTICS



PACKAGE MECHANICAL DATA



DO-214AC (SMA)

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.25	4.65	0.167	0.183
B	2.50	2.90	0.098	0.114
C	1.35	1.65	0.053	0.065
D	0.76	1.52	0.030	0.060
E	4.93	5.28	0.194	0.208
F	0.051	0.203	0.002	0.008
G	0.15	0.31	0.006	0.012
H	1.98	2.41	0.078	0.095
J	6.50		0.256	
K		2.30		0.090
L	1.70		0.067	

REEL SPECIFICATION

P/N	PKG	QTY
MBRA320T3G-MSTHRUMBRA310T3G-MS	DO-214AC (SMA)	5000

Attention

■ Any and all MSKSEMI Semiconductor products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your MSKSEMI Semiconductor representative nearest you before using any MSKSEMI Semiconductor products described or contained herein in such applications.

■ MSKSEMI Semiconductor assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specification of any and all MSKSEMI Semiconductor products described or contained herein.

■ Specifications of any and all MSKSEMI Semiconductor products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

■ MSKSEMI Semiconductor strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.

■ In the event that any or all MSKSEMI Semiconductor products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.

■ No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of MSKSEMI Semiconductor.

■ Information (including circuit diagrams and circuit parameters) herein is for example only ; it is not guaranteed for volume production. MSKSEMI Semiconductor believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringement of intellectual property rights or other rights of third parties.

■ Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the MSKSEMI Semiconductor product that you intend to use.